8-stage shift-and-store register LED driver

Rev. 1 — 7 August 2012

**Product data sheet** 

### 1. General description

The HEF4794B-Q100 is an 8-stage serial shift register. It has a storage latch associated with each stage for strobing data from the serial input (D) to the parallel LED driver outputs (QP0 to QP7). Data is shifted on the positive-going clock (CP) transitions. The data in each shift register stage is transferred to the storage register when the strobe input (STR) is HIGH. Data in the storage register appears at the outputs whenever the output enable input (OE) signal is HIGH.

Two serial outputs (QS1 and QS2) are available for cascading a number of HEF4794B-Q100 devices. Serial data is available at QS1 on positive-going clock edges to allow high-speed operation in cascaded systems with a fast clock rise time. The same serial data is available at QS2 on the next negative going clock edge. This is used for cascading HEF4794B-Q100 devices when the clock has a slow rise time.

It operates over a recommended  $V_{DD}$  power supply range of 3 V to 15 V referenced to  $V_{SS}$  (usually ground). Connect unused inputs to  $V_{DD}$ ,  $V_{SS}$ , or another input.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

### 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
   Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Fully static operation
- 5 V, 10 V, and 15 V parametric ratings
- Standardized symmetrical output characteristics
- ESD protection:
  - MIL-STD-833, method 3015 exceeds 2000 V
  - ◆ HBM JESD22-A114F exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)
- Complies with JEDEC standard JESD 13-B

### 3. Ordering information

#### Table 1.Ordering information

All types operate from  $-40 \ ^{\circ}\text{C}$  to  $+125 \ ^{\circ}\text{C}$ .

Type number	Package		
	Name	Description	Version
HEF4794BT-Q100	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1



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## 4. Functional diagram

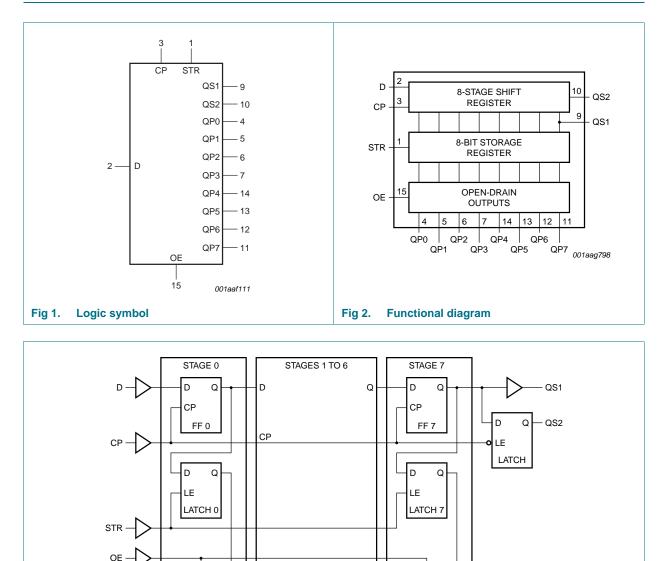


Fig 3.

Logic diagram

QP0

QP2

QP1

QP4

QP3

QP6

QP5

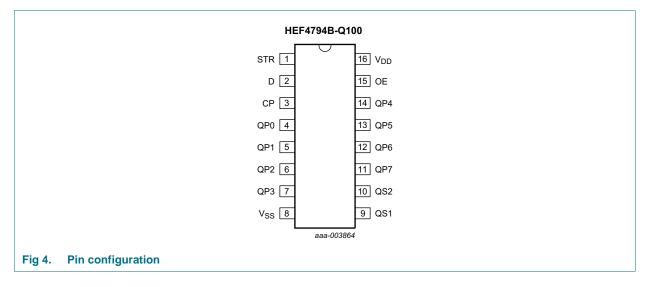
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QP7

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## 5. Pinning information

### 5.1 Pinning



## 5.2 Pin description

Table 2.	Pin description	
Symbol	Pin	Description
D	2	serial input
QP0 to QF	<b>2</b> 7 <b>4</b> , 5, 6, 7, 14, 13, 12, 1	1 parallel output
QS1	9	serial output
QS2	10	serial output
CP	3	clock input
STR	1	strobe input
OE	15	output enable input
V <sub>DD</sub>	16	supply voltage
V <sub>SS</sub>	8	ground (0 V)

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## 6. Functional description

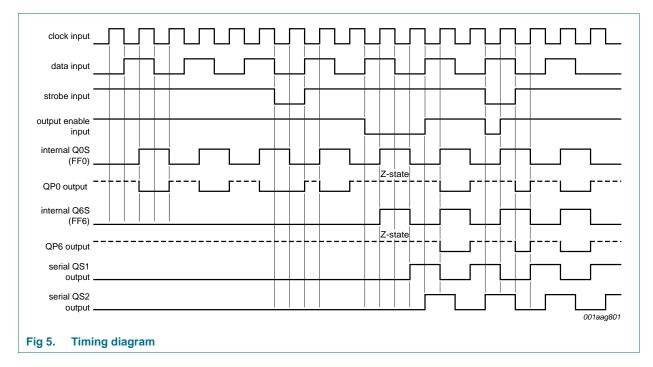
Input				Parallel outp	but	Serial output	ıt
СР	OE	STR	D	QP0	QPn	QS1[2]	QS2[3]
↑	L	х	Х	Z	Z	Q6S	no change
$\downarrow$	L	Х	Х	Z	Z	n.c.	Q7S
↑	Н	L	Х	no change	no change	Q6S	no change
↑	Н	Н	L	Z	QPn – 1	Q6S	no change
↑	Н	Н	Н	L	QPn – 1	Q6S	no change
$\downarrow$	Н	Н	Н	no change	no change	no change	Q7S

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state;

↑ = LOW-to-HIGH clock transition;  $\downarrow$  = HIGH-to-LOW clock transition.

[2] Q6S = the data in register stage 6 before the LOW to HIGH clock transition.

[3] Q7S = the data in register stage 7 before the HIGH to LOW clock transition.



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## 7. Limiting values

#### Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

		<b>J J I J</b>			
Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>DD</sub>	supply voltage		-0.5	+18	V
I <sub>IK</sub>	input clamping current	$V_{\rm I} < -0.5$ V or $V_{\rm I}$ > $V_{\rm DD}$ + 0.5 V	-	±10	mA
VI	input voltage		-0.5	V <sub>DD</sub> + 0.5	V
Ι <sub>ΟΚ</sub>	output clamping current	QSn outputs; V <sub>O</sub> < –0.5 V or V <sub>O</sub> > V <sub>DD</sub> + 0.5 V	-	±10	mA
		QPn outputs; $V_O < -0.5 V$	-	40	mA
l <sub>l</sub>	input leakage current		-	±10	mA
lo	output current	QSn outputs	-	±10	mA
		QPn outputs	-	40	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
T <sub>amb</sub>	ambient temperature		-40	+125	°C
P <sub>tot</sub>	total power dissipation	$T_{amb}$ = -40 °C to +125 °C	<u>[1]</u> _	500	mW
Р	power dissipation	per output	-	100	mW

[1] For SO16 package:  $P_{tot}$  derates linearly with 8 mW/K above 70 °C.

## 8. Recommended operating conditions

#### Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>DD</sub>	supply voltage		3	15	V
VI	input voltage		0	$V_{DD}$	V
T <sub>amb</sub>	ambient temperature	in free air	-40	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{DD} = 5 V$	-	3.75	μs/V
		V <sub>DD</sub> = 10 V	-	0.5	μs/V
		V <sub>DD</sub> = 15 V	-	0.08	μs/V

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## 9. Static characteristics

#### Table 6. Static characteristics

 $V_{SS} = 0$  V;  $V_{I} = V_{SS}$  or  $V_{DD}$ ; unless otherwise specified.

Symbol	Parameter	Conditions	$V_{DD}$	T <sub>amb</sub> =	–40 °C	T <sub>amb</sub> =	25 °C	T <sub>amb</sub> =	85 °C	T <sub>amb</sub> =	125 °C	Unit
				Min	Max	Min	Max	Min	Max	Min	Max	
V <sub>IH</sub>	HIGH-level	I <sub>O</sub>   < 1 μA	5 V	3.5	-	3.5	-	3.5	-	3.5	-	V
	input voltage		10 V	7.0	-	7.0	-	7.0	-	7.0	-	V
			15 V	11.0	-	11.0	-	11.0	-	11.0	-	V
V <sub>IL</sub>		$ I_0  < 1 \ \mu A$	5 V	-	1.5	-	1.5	-	1.5	-	1.5	V
	input voltage		10 V	-	3.0	-	3.0	-	3.0	-	3.0	V
			15 V	-	4.0	-	4.0	-	4.0	-	4.0	V
V <sub>OH</sub>	HIGH-level	QSn outputs;	5 V	4.95	-	4.95	-	4.95	-	4.95	-	V
	output voltage	$ I_0  < 1 \ \mu A$	10 V	9.95	-	9.95	-	9.95	-	9.95	-	V
			15 V	14.95	-	14.95	-	14.95	-	14.95	-	V
V <sub>OL</sub>	LOW-level	QSn outputs;	5 V	-	0.05	-	0.05	-	0.05	-	0.05	V
	output voltage	<b>I</b> <sub>O</sub>   < 1 μA	10 V	-	0.05	-	0.05	-	0.05	-	0.05	V
			15 V	-	0.05	-	0.05	-	0.05	-	0.05	V
		QPn outputs;	5 V	-	0.75	-	0.75	-	1.5	-	1.5	V
		I <sub>O</sub>   < 20 mA	10 V	-	0.75	-	0.75	-	1.5	-	1.5	V
			15 V	-	0.75	-	0.75	-	1.5	-	1.5	V
I <sub>OH</sub>	HIGH-level	QSn outputs										
	output current	$V_O = 2.5 V$	5 V	-	-1.7	-	-1.4	-	-1.1	-	-1.1	mA
		$V_{O} = 4.6 V$	5 V	-	-0.64	-	-0.5	-	-0.36	-	-0.36	mA
		$V_{O} = 9.5 V$	10 V	-	-1.6	-	-1.3	-	-0.9	-	-0.9	mA
		V <sub>O</sub> = 13.5 V	15 V	-	-4.2	-	-3.4	-	-2.4	-	-2.4	mA
I <sub>OL</sub>	LOW-level	QSn outputs										
	output current	$V_O = 0.4 V$	5 V	0.64	-	0.5	-	0.36	-	0.36	-	mA
		$V_{O} = 0.5 V$	10 V	1.6	-	1.3	-	0.9	-	0.9	-	mA
		V <sub>O</sub> = 1.5 V	15 V	4.2	-	3.4	-	2.4	-	2.4	-	mA
l <sub>l</sub>	input leakage current		15 V	-	±0.1	-	±0.1	-	±1.0	-	±1.0	μA
I <sub>OZ</sub>	OFF-state	QPn output	5 V	-	2	-	2	-	15	-	15	μA
	output current	is HIGH; V <sub>O</sub> = 15 V	10 V	-	2	-	2	-	15	-	15	μA
		v0 = 13 v	15 V	-	2	-	2	-	15	-	15	μA
I <sub>DD</sub>	supply current	I <sub>O</sub> = 0 A	5 V	-	5	-	5	-	150	-	150	μA
			10 V	-	10	-	10	-	300	-	300	μA
			15 V	-	20	-	20	-	600	-	600	μA
Cı	input capacitance		-	-	-	-	-	7.5	-	-	-	pF

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# **10. Dynamic characteristics**

Symbol	Parameter	Conditions	V <sub>DD</sub>		Extrapolation formula	Min	Тур	Max	Unit
t <sub>PHL</sub>	HIGH to LOW	CP to QS1;	5 V	[1]	132 ns + (0.55 ns/pF)C <sub>L</sub>	-	160	320	ns
	propagation delay	see <u>Figure 6</u>	10 V		53 ns + (0.23 ns/pF)C <sub>L</sub>	-	65	130	ns
			15 V		37 ns + (0.16 ns/pF)C <sub>L</sub>	-	45	90	ns
		CP to QS2;	5 V		92 ns + (0.55 ns/pF)C <sub>L</sub>	-	120	240	ns
		see <u>Figure 6</u>	10 V		39 ns + (0.23 ns/pF)C <sub>L</sub>	-	50	100	ns
			15 V		32 ns + (0.16 ns/pF)C <sub>L</sub>	-	40	80	ns
PLH	LOW to HIGH	CP to QS1;	5 V	[1]	102 ns + (0.55 ns/pF)C <sub>L</sub>	-	130	260	ns
	propagation delay	see <u>Figure 6</u>	10 V		44 ns + (0.23 ns/pF)C <sub>L</sub>	-	55	110	ns
			15 V		32 ns + (0.16 ns/pF)C <sub>L</sub>	-	40	80	ns
	CP to QS2;	5 V		102 ns + (0.55 ns/pF)C <sub>L</sub>	-	130	260	ns	
		see Figure 6	10 V		49 ns + (0.23 ns/pF)C <sub>L</sub>	-	60	120	ns
		15 V		37 ns + (0.16 ns/pF)C <sub>L</sub>	-	45	90	ns	
PZL	OFF-state to LOW	CP to QPn;	5 V			-	240	480	ns
propagation delay	see Figure 6	10 V			-	80	160	ns	
			15 V			-	55	110	ns
		STR to QPn;	5 V			-	140	280	ns
		see Figure 7	10 V			-	70	140	ns
			15 V			-	55	110	ns
PLZ	LOW to OFF-state	CP to QPn;	5 V			-	170	340	ns
	propagation delay	see Figure 6	10 V			-	75	150	ns
			15 V			-	60	120	ns
		STR to QPn;	5 V			-	100	200	ns
		see Figure 7	10 V			-	40	100	ns
			15 V			-	35	70	ns
en	enable time	OE to QPn;	5 V	[2]		-	100	200	ns
		see Figure 8	10 V			-	55	110	ns
			15 V			-	50	100	ns
dis	disable time	OE to QPn;	5 V	[2]		-	80	160	ns
		see Figure 8	10 V			-	40	80	ns
			15 V			-	30	60	ns
	transition time	QS1, QS2;	5 V	[1]	35 ns + (1.00 ns/pF)C <sub>L</sub>	-	85	170	ns
		see Figure 6	10 V	[3]	19 ns + (0.42 ns/pF)C <sub>L</sub>	-	40	80	ns
			15 V		16 ns + (0.28 ns/pF)C <sub>L</sub>	-	30	60	ns

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Symbol	Parameter	Conditions	V <sub>DD</sub>	Extrapolation formula	Min	Тур	Max	Unit
t <sub>W</sub>	pulse width	CP; LOW and	5 V		60	30	-	ns
		HIGH;	10 V		30	15	-	ns
	see <u>Figure 6</u>	15 V		24	12	-	ns	
	STR; HIGH;	5 V		80	40	-	ns	
		see <u>Figure 7</u>	10 V		60	30	-	ns
			15 V		24	12	-	ns
t <sub>su</sub>	su set-up time D to CP;	,	5 V		60	30	-	ns
		see <u>Figure 9</u>	10 V		20	10	-	ns
			15 V		15	5	-	ns
t <sub>h</sub>	hold time	D to CP;	5 V		+5	-15	-	ns
		see <u>Figure 9</u>	10 V		20	5	-	ns
			15 V		20	5	-	ns
f <sub>clk(max)</sub>	<sub>lk(max)</sub> maximum clock CP; see Figure	CP; see Figure 6	5 V		5	10	-	MHz
	frequency	iency	10 V		11	22	-	MHz
			15 V		14	28	-	MHz

# Table 7. Dynamic characteristics ... continued $V_{22} = 0$ $V_{23}$ $V_{23}$

**—**: 10

[1] The typical values of the propagation delay and transition times are calculated from the extrapolation formulas shown (C<sub>L</sub> in pF).

[2]  $t_{en}$  is the same as  $t_{PZL}$  and  $t_{dis}$  is the same as  $t_{PLZ}$ 

[3]  $t_t$  is the same as  $t_{TLH}$  and  $t_{THL}$ 

#### Dynamic power dissipation Table 8.

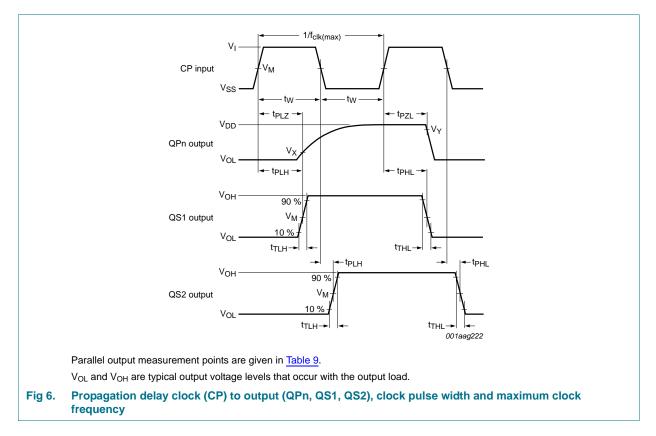
 $P_D$  can be calculated from the formulas shown.  $V_{SS} = 0$  V;  $t_r = t_f \le 20$  ns;  $T_{amb} = 25$  °C.

Symbol	Parameter	$V_{DD}$	Typical formula	Where
PD	dynamic power dissipation	5 V	$\label{eq:posterior} P_D = 1200 \times f_i + \Sigma (f_o \times C_L) \times V_DD{}^2 \; \mu W$	$f_i = input frequency in MHz;$
		10 V	$P_D = 5550 \times f_i + \Sigma (f_o \times C_L) \times V_DD{}^2 \ \mu W$	$f_o = output frequency in MHz;$
		15 V	$\label{eq:posterior} \textbf{P}_{D} = \textbf{15000} \times \textbf{f}_{i} + \boldsymbol{\Sigma}(\textbf{f}_{o} \times \textbf{C}_{L}) \times \textbf{V}_{DD}{}^{2} \; \boldsymbol{\mu} \textbf{W}$	$C_L$ = output load capacitance in pF;
				$\Sigma(f_o \times C_L)$ = sum of the outputs;
				V <sub>DD</sub> = supply voltage in V.

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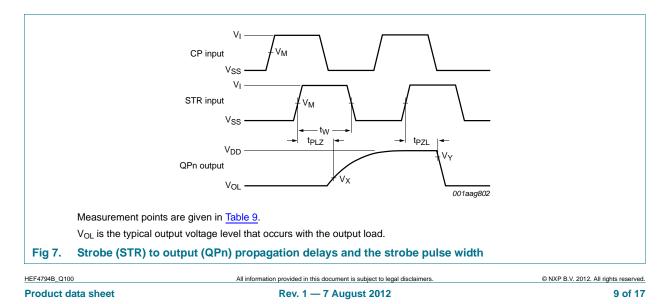
8-stage shift-and-store register LED driver

## 11. Waveforms



#### Table 9. Measurement points

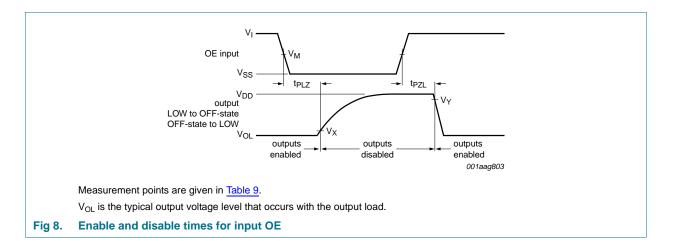
Supply	Input	Output		
V <sub>DD</sub>	V <sub>M</sub>	V <sub>M</sub>	V <sub>X</sub>	V <sub>Y</sub>
5 V to 15 V	0.5V <sub>DD</sub>	0.5V <sub>DD</sub>	0.1V <sub>O</sub>	0.9V <sub>O</sub>

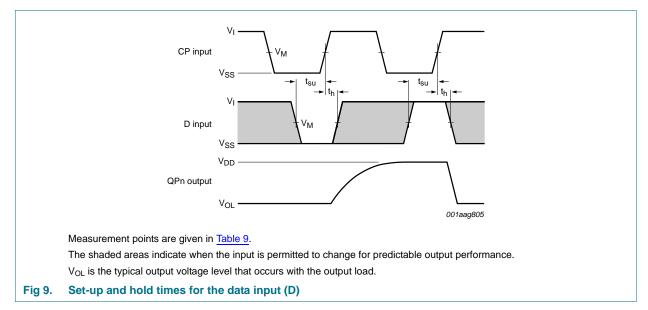


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#### 8-stage shift-and-store register LED driver



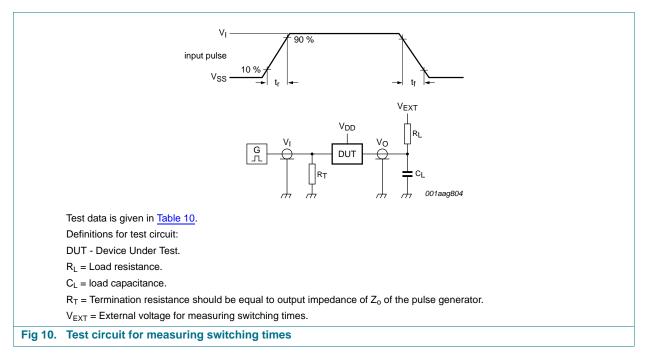


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Load

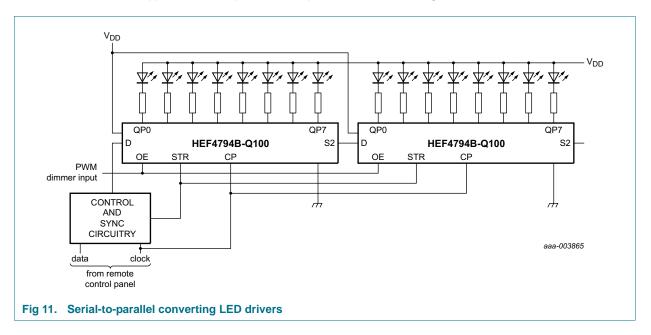


# Table 10. Test data Supply Input V<sub>EXT</sub>

Supply	input		VEXT		Luau	
V <sub>DD</sub>	VI	t <sub>r</sub> , t <sub>f</sub>	t <sub>PLZ</sub> , t <sub>PZL</sub>	t <sub>PLH</sub> , t <sub>PHL</sub>	CL	RL
5 V to 15 V	V <sub>DD</sub>	≤ 20 ns	V <sub>DD</sub>	open	50 pF	1 kΩ

8-stage shift-and-store register LED driver

# **12.** Application information

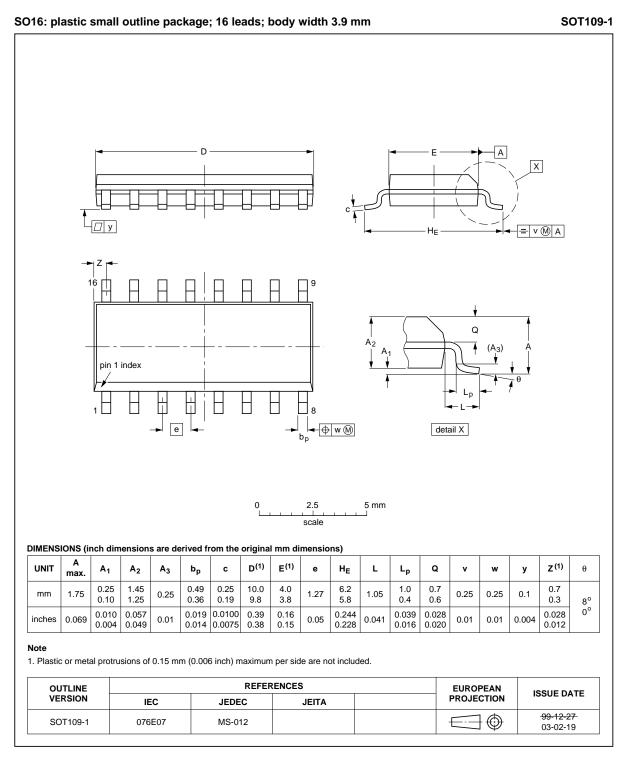


Application example: serial-to-parallel data converting LED drivers.

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## 13. Package outline



#### Fig 12. Package outline SOT109-1 (SO16)

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## 14. Abbreviations

Table 11. Ab	able 11. Abbreviations				
Acronym	Description				
НВМ	Human Body Model				
ESD	ElectroStatic Discharge				
MM	Machine Model				
MIL	Military				

# 15. Revision history

Table 12. Revision history					
Document ID	Release date	Data sheet status	Change notice	Supersedes	
HEF4794B_Q100 v.1	20120807	Product data sheet	-	-	

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### 16. Legal information

### 16.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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### 8-stage shift-and-store register LED driver

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